Thick Film Hybrid IC



# Features

- Small-sized package permitting audio sets to be made slimmer (up to 70W)
- The STK4024Vseries are available for output 20W to 100W (200W) and are pin-compatible. (120W to 200W : 18 pins)
- Facilitates thermal design of slim stereo sets.
- Distortion 0.08% due to current mirror circuit
- Possible to design electronic supplementary circuits (pop noise muting at the time of power ON/OFF, load short protector, thermal shutdown)

## **Package Dimensions**

unit: mm

4062



# **Specifications**

### **Maximum Ratings** at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>CC</sub> max		±62	V
Thermal resistance	Өј-с		1.4	°C/W
Junction Temperature	Tj		150	°C
Operating substrate temperature	Tc		125	°C
Storage temperature	Tstg		-30 to +125	°C
Available time for load short-circuit	t <sub>s</sub> *1	$V_{CC} = \pm 42V$ , $R_L = 8\Omega$ , f = 50Hz, Po = 70W	1	S

## **Recommended Operating Conditions** at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V <sub>CC</sub>		<u>±42</u>	V
Load resistance	RL		8	Ω

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# $\begin{array}{ll} \textbf{Operating Characteristics} & \text{at } Ta=25^\circ\text{C}, \, V_{CC}=\pm42\text{V}, \, R_L=8\Omega, \, \text{VG}=40\text{dB}, \, \text{Rg}=600\Omega, \\ & 100\text{kHz LPF ON}, \, R_L: \text{noninductive load} \end{array}$

Parameter	Symbol	Conditions	min	typ	max	Unit
Quiescent current	lcco	V <sub>CC</sub> = ±50.5V	15		120	mA
Output power	Po (1)	THD = 0.08%, f = 20Hz to 20kHz	70			W
	Po (2)	$V_{CC} = \pm 36 \text{V}, \text{THD} = 0.2\%,$ $R_L = 4\Omega, \text{ f} = 1 \text{kHz}$	70			W
Total harmonic distortion	THD	Po = 1.0W, f = 1kHz			0.08	%
Frequency response	f <sub>L</sub> , f <sub>H</sub>	Po = 1.0W, $^{+0}_{-3}$ dB		20 to 50k		Hz
Input impedance	r <sub>i</sub>	Po = 1.0W, f = 1kHz		55		kΩ
Output noise voltage	V <sub>NO</sub> *2	$V_{CC}$ = ±50.5V, Rg = 10k $\Omega$			1.2	mVrms
Neutral voltage	V <sub>N</sub>	$V_{CC} = \pm 50.5 V$	-70	0	+70	mV

Notes. For power supply at the time of test, use a constant-voltage power supply unless otherwise specified.

\*1 For measurement of the available time for load short-circuit and output noise voltage, use the specified transformer power supply shown right.

\*2 The output noise voltage is represented by the peak value on rms scale (VTVM) of average value indicating type. The noise voltage waveform includes no flicker noise.



Specified Transformer Power Supply (Equivalent to MG-200)

# **Equivalent Circuit**





# Sample Application Circuit: 70W min Single-Channel AF Power Amplifier

# Sample Printed Circuit Pattern for Application Circuit (Cu-foiled side)









**Description of External Parts** 



#### **STK4040V**

R1, C1	Input filter circuit • Used to reduce noise at high frequencies.		
C2	Input coupling capacitor • Used to block DC current. When the reactance of the capacitor increases at low frequencies, the dependence of 1/f noise on signal source resistance causes the output noise to worsen. It is better to decrease the reactance.		
R2	Input bias resistor Used to bias the input pin to zero. Affects V <sub>N</sub> stability. (See NF circuit.) Because of differential input, this resistor fixes the input resistance practically.		
	NFB circuit (AC NF circuit). It is desirable that the error of the resistor value is 1% or less.		
R4, R5 C3 (R2)	$I_{R_{2}} = \frac{1}{2\pi \cdot R_{4} \cdot C_{3}} I_{R_{5}} I_{R_{5$		
R3	Differential constant-current bias resistor		
R6, R7	Used for oscillation blocking and phase compensation		
R7, C4	Used for oscillation blocking and phase compensation (C4 : A polyester film capacitor is recommended.)		
C6, C9	Used for oscillation blocking and phase compensation Power amp stage (Must be connected near the pin) C6 : Power amp on (+) side C9 : Power amp on (-) side		
C8	Used for oscillation blocking and phase compensation (Used for oscillation blocking before clip at power amp stage)		
C5	Used for oscillation blocking and distortion improvement		
R8, C10	Ripple filter circuit on (+) side		
R9, C13	Ripple filter circuit on (-) side		
C11, C12	Used for oscillation blocking Used to decrease the power supply impedance to operate the IC stably. Must be connected near the IC pin. It is desirable to use an electrolytic capacitor.		



Sample Application Circuit (protection circuit and muting circuit)

# **Thermal Design**

The IC power dissipation of the STK4040V at the IC-operated mode is 47.4W max. at load resistance  $8\Omega$  and 70.5W max. at load resistance  $4\Omega$  for continuous sine wave as shown in Figure 1 and 2.



In an actual application where a music signal is used, it is impractical to estimate the power dissipation based on the continuous signal as shown above, because too large a heat sink must be used. It is reasonable to estimate the power dissipation as 1/10 Po max. (EIAJ).

That is, Pd = 30.6W at  $8\Omega$ , Pd = 38.2W at  $4\Omega$ 

Thermal resistance  $\theta$ c-a of a heat sink for this IC power dissipation (Pd) is fixed under conditions 1 and 2 shown below.

Condition 1:  $T_C = Pd \times \theta c \cdot a + Ta \le 125^{\circ}C$  .....(1) where Ta : Specified ambient temperature  $T_C :$  Operating substrate temperature

 $\begin{array}{lll} \mbox{Condition 2:} & Tj = Pd \times (\theta c \text{-}a) + Pd/2 \times (\theta j \text{-}c) + Ta \leq 150^{\circ} C.....(2) \\ & \mbox{where} & Tj : Junction temperature of power transistor \\ \end{array}$ 

Assuming that the power dissipation is shared equally between the two power transistors, thermal resistance  $\theta_{j-c}$  is  $1.4^{\circ}C/W$  and

$$Pd \times (\theta c - a + 1.4/2) + Ta \le 150^{\circ}C$$
.....(3)

Thermal resistance  $\theta$ c-a of a heat sink must satisfy inequalities (1) and (3).

Figure 3 shows the relation between Pd and  $\theta$ c-a given from (1) and (3) with Ta as a parameter.



This design is based on the use of a constant-voltage regulated power supply. Pd differs when a transformer power supply is used. Redesign must be made based on Pd that suits the regulation of each transformer.

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